

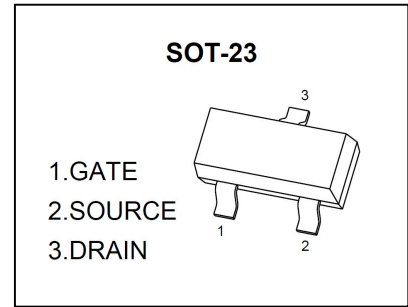


## SOT-23 Plastic-Encapsulate MOSFET

**CJ2202** P-Channel MOSFET

### Key Performance Parameters

$V_{BR(DSS)}$	$R_{DS(on)}$ TYP	$I_D$
-20V	18mΩ@-4.5V	-6.2A
	22mΩ@-2.5V	



### DESCRIPTION

This advanced technology has been especially tailored to minimize on-state resistance, provide superior switching performance.

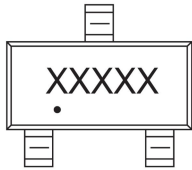
### FEATURES

- Battery switch
- Load switch
- High density cell design for ultra low  $R_{DS(ON)}$

### APPLICATIONS

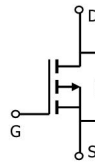
- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply

### MARKING



XXXXX = 102  
Solid dot = Green molding compound device

### EQUIVALENT CIRCUIT



### ABSOLUTE MAXIMUM RATINGS ( $T_J=25^\circ\text{C}$ unless otherwise specified )

Parameter		Symbol	Value	Unit
Drain-Source Voltage		$V_{DS}$	-20	V
Gate-Source Voltage		$V_{GS}$	±12	V
Continuous Drain Current	$T_A = 25^\circ\text{C}$	$I_D^{\text{⑤}}$	-6.2	A
	$T_A = 75^\circ\text{C}$		-5	
Pulsed Drain Current		$I_{DM}^{\text{①②}}$	-24.8	A
Power Dissipation		$P_D^{\text{①⑤}}$	1.25	W
Operating Junction and Storage Temperature Range		$T_J, T_{stg}$	-55~+150	°C

### Thermal Characteristics

Parameter	Symbol	Value		Unit
		Typ	Max	
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{\text{⑥}}$	76	100	°C/W
		Steady State	110	145

# Typical Characteristics

## ELECTRICAL CHARACTERISTICS ( $T_J=25^{\circ}\text{C}$ unless otherwise specified)

### Static Characteristics

Parameter	Symbol	Test Condition	Value			Unit	
			Min	Typ	Max		
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS}=0V, I_D=-250\mu A$	-20	-	-	V	
Zero gate voltage drain current	$I_{DSS}$	$V_{DS}=-20V, V_{GS}=0V$	$T_J=25^{\circ}\text{C}$	-	-	-1.0	$\mu A$
			$T_J=125^{\circ}\text{C}$	-	-	-100	
Gate-body leakage current	$I_{GSS}$	$V_{GS}=\pm 12V, V_{DS}=0V$	-	-	$\pm 100$	nA	
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}, I_D=-250\mu A$	-0.45	-0.67	-1.0	V	
Static drain-source on-state resistance	$R_{DS(on)}^{(3)}$	$V_{GS}=-4.5V, I_D=-6.2A$	$T_J=25^{\circ}\text{C}$	-	18	22	m $\Omega$
			$T_J=125^{\circ}\text{C}$	-	24	29	
		$V_{GS}=-2.5V, I_D=-6.2A$		22	27		
Forward transconductance	$g_{FS}$	$V_{DS}=-5V, I_D=-3.3A$	-	11	-	S	

### Dynamic Characteristics<sup>(4)</sup>

Input capacitance	$C_{iss}$	$V_{GS}=0V, V_{DS}=-10V,$ $f=1\text{MHz}$	-	1428	-	pF
Output capacitance	$C_{oss}$		-	195	-	
Reverse transfer capacitance	$C_{rss}$		-	181	-	
Total gate charge	$Q_g$	$V_{GS}=-4.5V, V_{DS}=-10V, I_D=-3.3A$	-	17.5	-	nC
Gate charge at threshold	$Q_{G(th)}$		-	1.2	-	
Gate-source charge	$Q_{gs}$		-	2.4	-	
Gate-drain charge	$Q_{gd}$		-	3.3	-	
Turn-on delay time	$t_{d(on)}$	$V_{DD}=-6V, V_{GS}=-4.5V,$ $R_L=6\Omega, R_g=6\Omega$	-	5.2	-	ns
Turn-on rise time	$t_r$		-	3.8	-	
Turn-off delay time	$t_{d(off)}$		-	79	-	
Turn-off fall time	$t_f$		-	28	-	

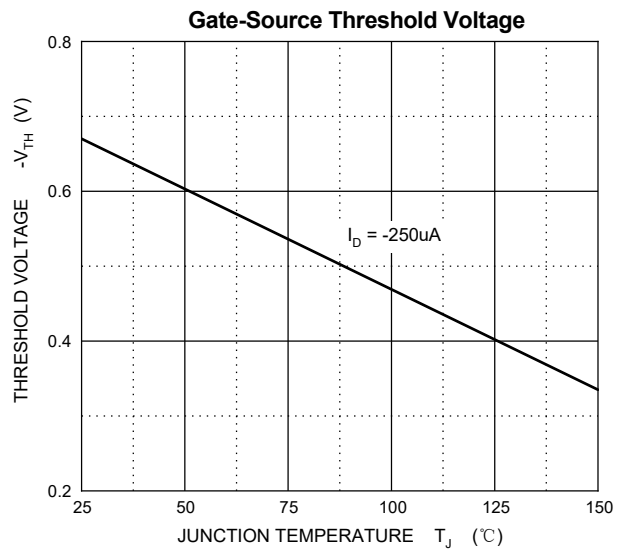
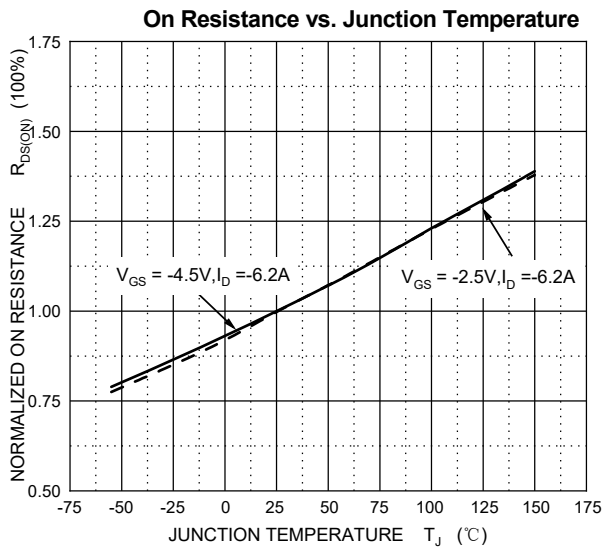
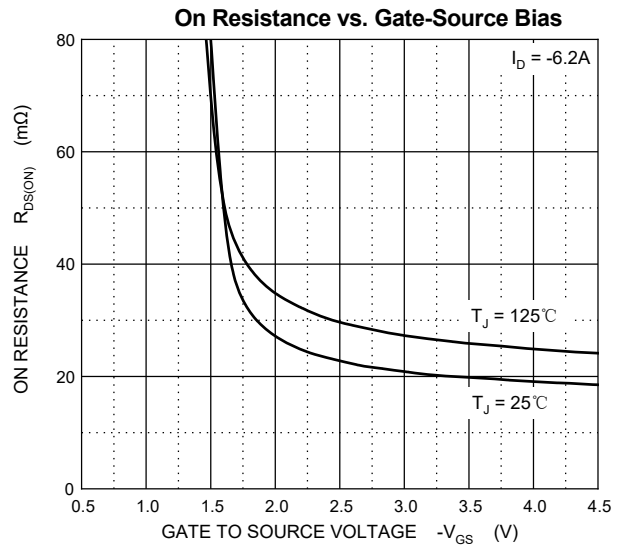
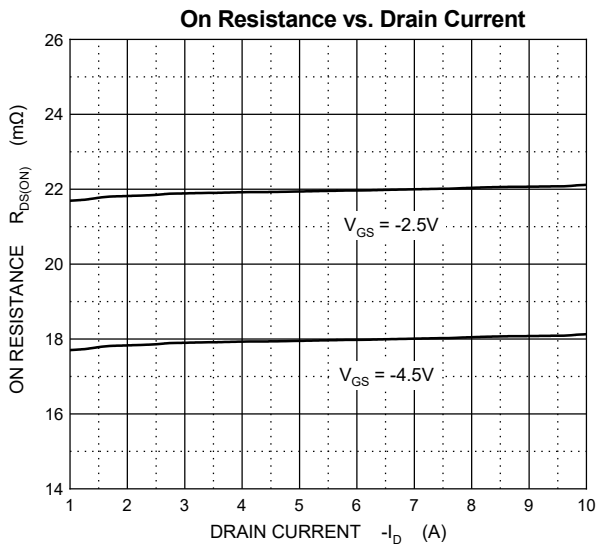
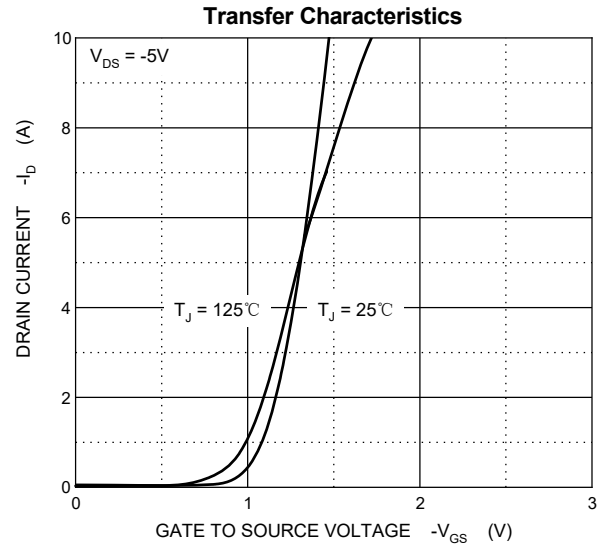
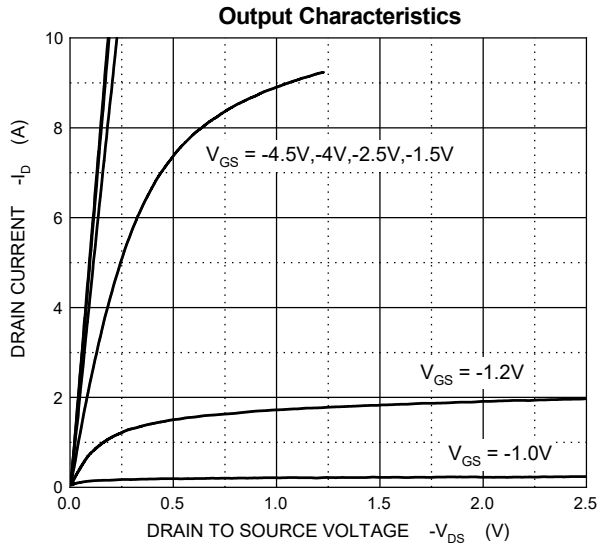
### Reverse Diode Characteristics

Drain-source diode forward voltage	$V_{SD}^{(3)}$	$V_{GS}=0V, I_S=-2A$	-	-	-1.2	V
Continuous drain-source diode forward current	$I_S^{(1)}$		-	-	-6.2	A
Pulsed drain-source diode forward current	$I_{SM}^{(1)(2)}$		-	-	-24.8	A

#### Notes:

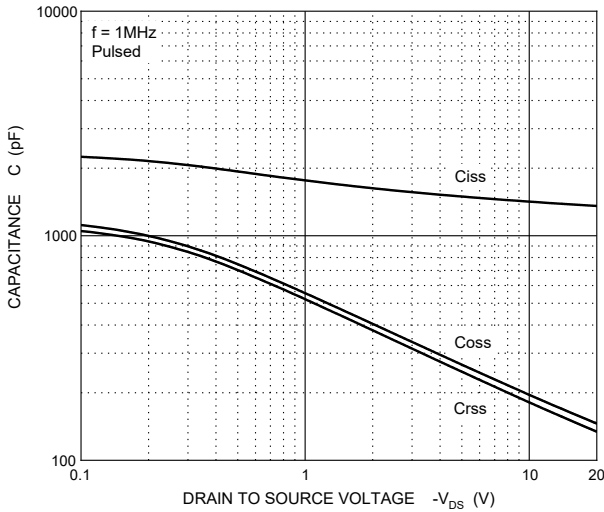
- ①.Limited only by maximum temperature allowed.
- ②. $P_W \leq 10\mu s$ , Duty cycle  $\leq 1\%$ .
- ③.Pulse Test : Pulse Width  $\leq 380\mu s$ , duty cycle  $\leq 2\%$ .
- ④.Guaranteed by design, not subject to production.
- ⑤.Device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. double-sided Copper, in a still air environment with  $T_A=25^{\circ}\text{C}$ .The current rating is based on the  $t \leq 10s$  thermal resistance rating.

# Typical Characteristics

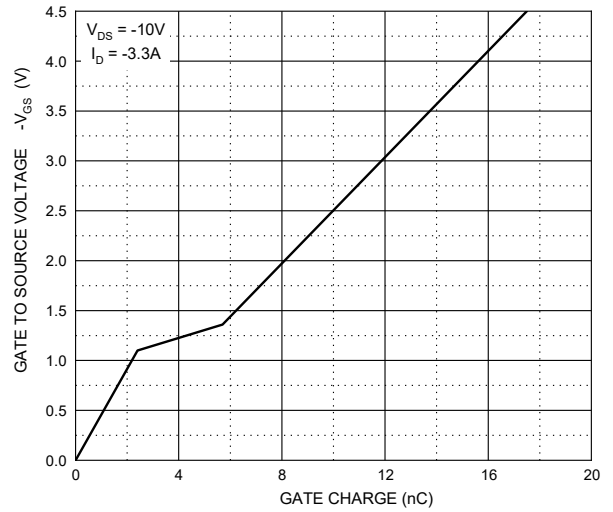


# Typical Characteristics

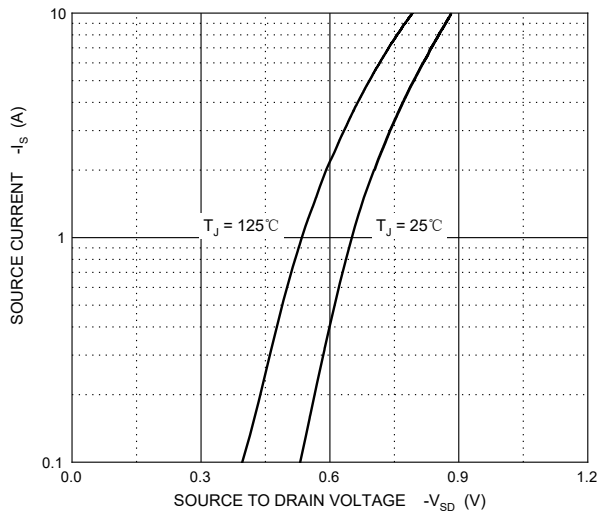
Typical Capacitances



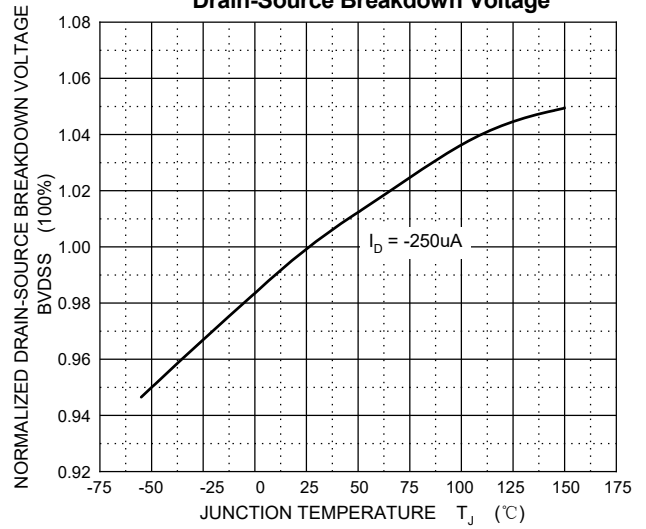
Gate Charge



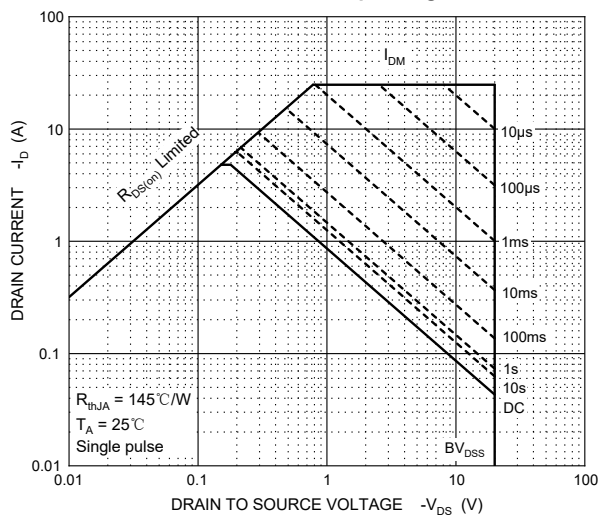
Source-Drain Diode Forward Characteristics



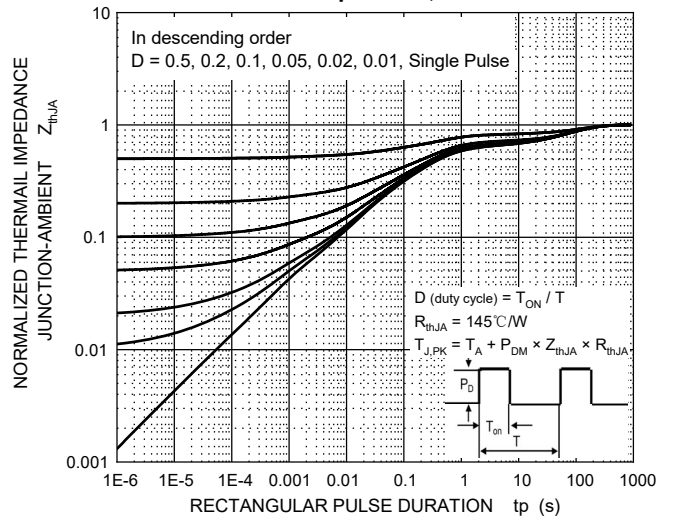
Drain-Source Breakdown Voltage



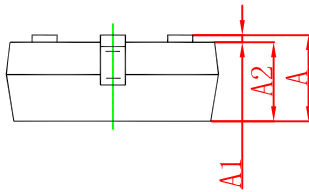
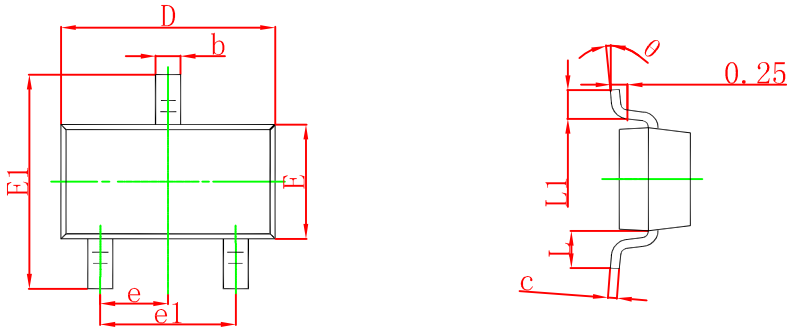
Maximum Safe Operating Area



Transient Thermal Impedance, Junction-Ambient

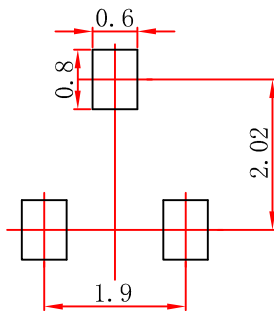


## SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

## SOT-23 Suggested Pad Layout



**Note:**

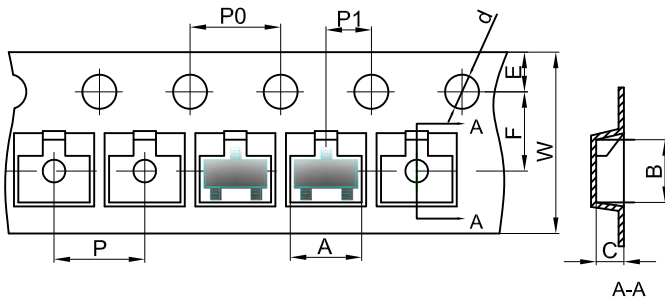
1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05\text{mm}$ .
3. The pad layout is for reference purposes only.

**NOTICE**

JSCJ reserves the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JSCJ does not assume any liability arising out of the application or use of any product described herein.

# SOT-23 Tape and Reel

## SOT-23 Embossed Carrier Tape



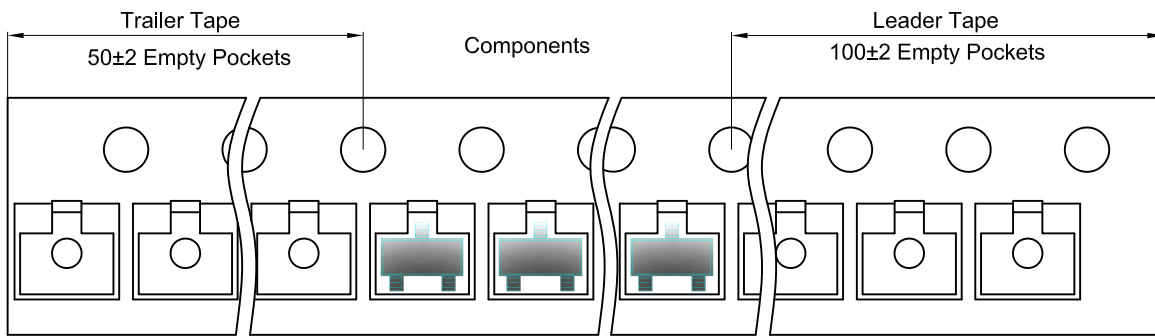
### Packaging Description:

SOT-23 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

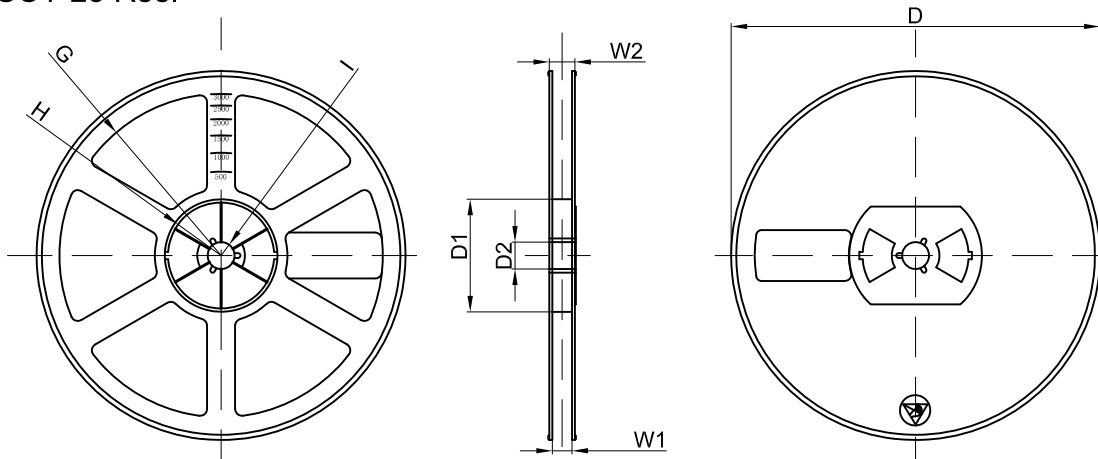
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-23	3.15	2.77	1.22	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

## SOT-23 Tape Leader and Trailer



## SOT-23 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7"Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	